

/ Descriptions

Triac in a TO-263 Plastic Package.

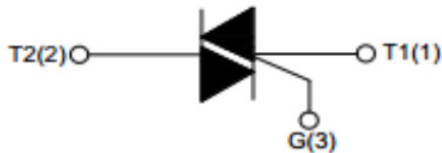
/ Features

Medium current triac, Low on state voltage drop,High reliability and stability,Low thermal resistance, HF Product.

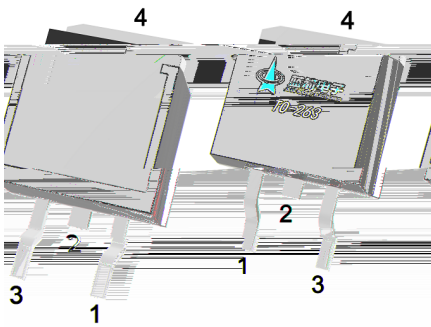
/ Applications

Suitable for general purpose AC switching .Such as static relays,heating regulation,induction motor starting circuits,motor speed controllers,etc.

/ Equivalent Circuit



/ Pinning



PIN1 Main Terminal 1 PIN 2 4 Main Terminal 2 PIN 3 Gate

/ Marking

See Marking Instructions.

/ Absolute Maximum Ratings(Ta=25)

Parameter	Symbol	Rating	Unit
Repetitive peak off-state/reverse voltages(T _j =125)	V _{DRM} /V _{RPM}	800	V
RMS on-state current(T _C =110)	I _{T(RMS)}	8	A
Non repetitive surge peak on-state current(full cycle, T _j =25°C)	I _{TSM(t=20ms)}	80	A
I ² t value for fusing(T _j =25)	I ² t _(tp=10ms)	36	A ² s
Critical rate of rise of on-state current (I _G =2I _{GT} , f=120Hz T _j =125)	dI/dt I-II-III	50	A/μs
Peak gate current(t _p =20μs T _j =125)	I _{GM}	4.0	A
Average gate power dissipation(T _j =125)	P _{G(AV)}	1	W
Operating junction temperature range	T _j	-40 125	
Storage junction temperature range	T _{stg}	-40 150	
Junction to ambient(AC)	R _{th(j-a)}	60	/W
Junction to case for(AC)	R _{th(j-c)}	1.6	

/ Electrical Characteristics(T_j=25)

3 / Snubberless and logic level 3 quadrants)

Symbol	Test Conditions	Quadrant	Value		Unit
I _{GT}	V _D =12V R _L =30	I-II-III	Max.	35	mA
V _{GT}	V _D =12V R _L =30	I-II-III	Max.	1.3	V
V _{GD}	V _D =V _{DRM} R _L =3.3K T _j =125	I-II-III	Min.	0.2	V
I _L	I _G =1.2I _{GT}	I-III	Max.	50	mA
		II		60	
I _H	I _T =100mA		Max.	35	mA
(dV/dt)	V _D =67% V _{DRM} Gate Open	T _j =125	Min.	400	V/μs
V _{TM}	I _{TM} =11A t _p =380μs	T _j =25	Max.	1.55	V
I _{DRM}	V _D =V _{DRM} V _R =V _{RPM}	T _j =25		10	μA
I _{RPM}		T _j =125		1	mA

/ Electrical Characteristic Curve

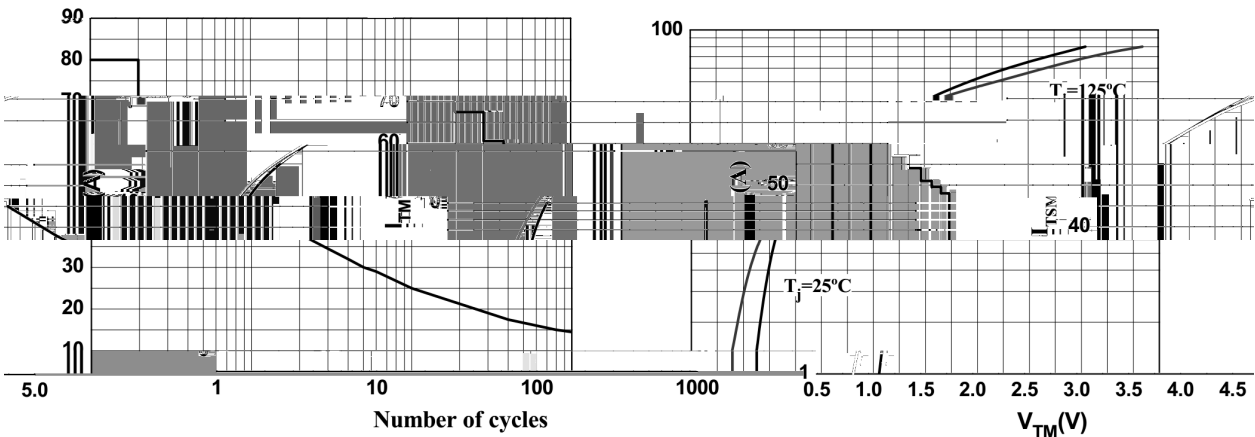
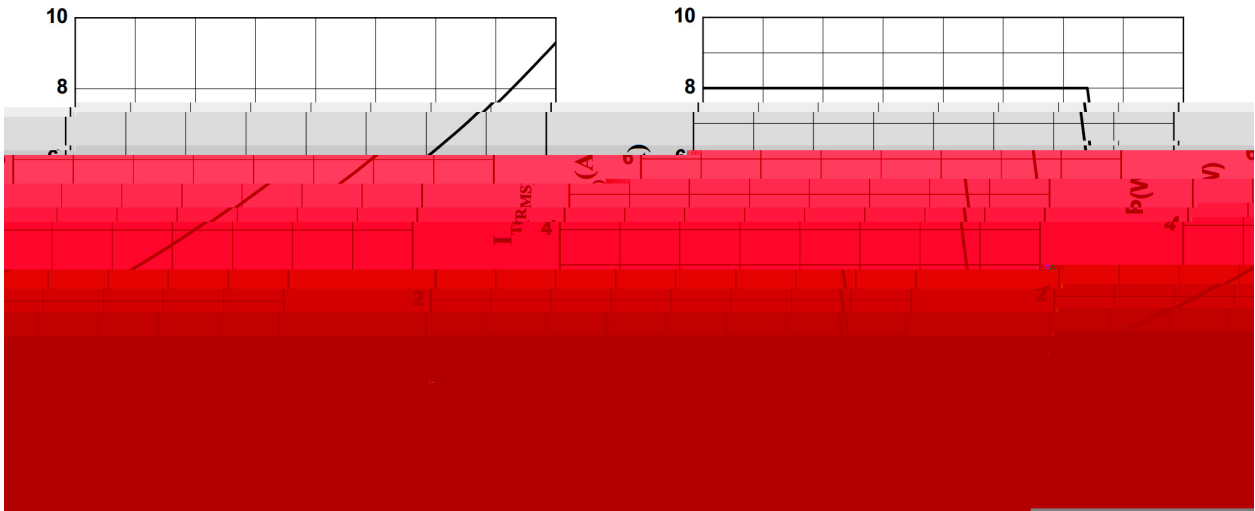


FIG.3: Surge peak on-state current versus number of cycles

FIG.4: On-state characteristics

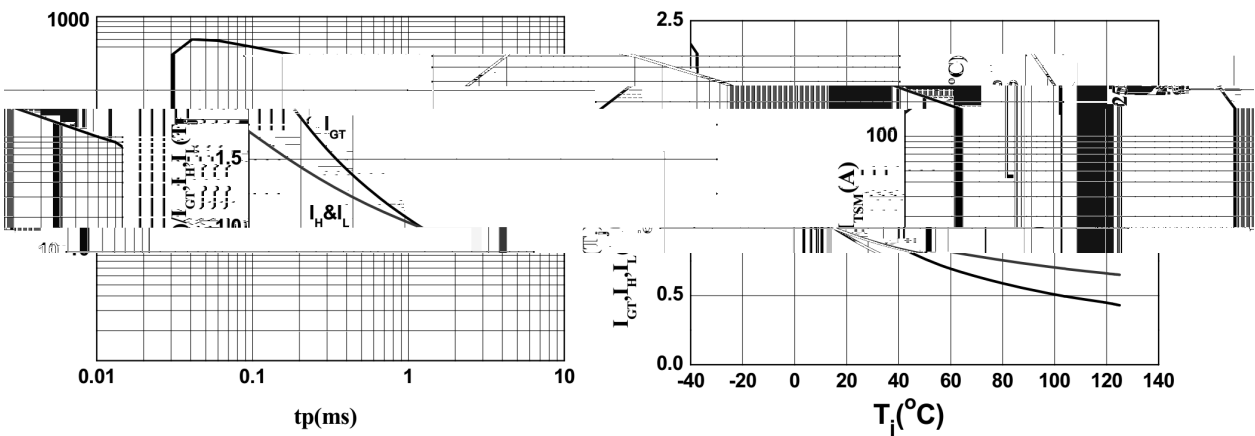
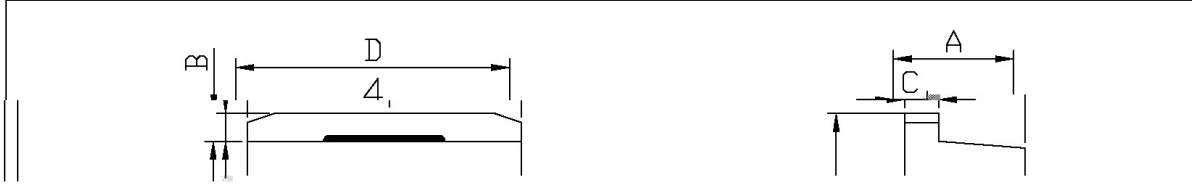


FIG.5: Non-repetitive surge peak on-state current versus pulse width (for a sinusoidal pulse with width $t_p=10\mu s$ and corresponding value of $di/dt < 100A/\mu s$)

FIG.6: On-state current versus junction temperature

/ Package Dimensions

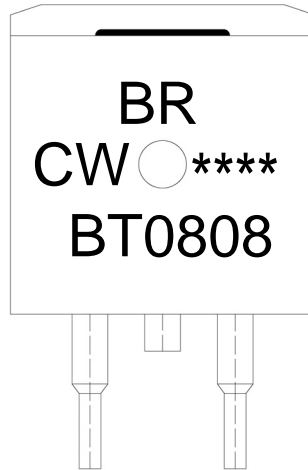


单位: mm

Symbol	Dimensions in Millimeters		Symbol	Dimensions in Millimeters	
	Min	Max		Min	Max
A	4.30	4.70	F _L	0.00	0.40
B	1.00	1.40	e1	2.24	2.74
b	0.70	0.90	e2	4.88	5.38
b1	1.15	1.35	L1	15.00	16.00
b2	0.40	0.60	L2	2.24	2.74
C	1.20	1.40	L3	1.20	1.40
D	9.80	10.20			

TP-263

/ Marking Instructions



Note:

BR: Company Code

CW: I_{GT} Bracket code

****: Lot No. Code, code change with Lot No

BT0808: Product Type Code

BRBT0808CWBD
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